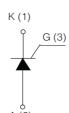


TO-261AA (SOT-223)





On-State Current

Gate Trigger Current

1.25 Amp

 $< 200 \, \mu A$

Off-State Voltage

400 V ÷ 800 V

FEATURES

- Glass/passivated die junctions
- Low current SCR
- Low thermal resistance
- High surge current capability
- Low forward voltage drop
- Solder dip 260°C, 10s
- Component in accordance to RoHS 2011/65/EU and WEEE 2002/96/EC
- Meets MSL level 3, per J-STD-020, LF maximum peak of 260° C

MECHANICAL DATA

- Case: TO-261AA (SOT-223). Epoxy meets UL 94V-0 flammability rating.
- Polarity: As marked on the body.
- **Terminals:** Matte tin plated leads, solderable per MIL-STD-750 Method 2026, J-STD-002 and JESD22-B102. Consumer grade, meets JESD 201 class 1A whisker test.

TYPICAL APPLICATIONS

Thanks to highly sensitive triggering levels, the FS02xxxN SCR series is suitable for all applications where available gate current is limited, such as ground fault circuit interruptors, pilot circuits in solid state relays, stand-by mode power supplies, smoke and alarm detectors.

Maximun Ratings and Electrical Characteristics at 25°C

SYMBOL	PARAMETER	CONDITIONS	Value	Unit
I _{T(RMS)}	On-state Current	180 ° Conduction Angle, T _C = 115 °C	1.25	А
I _{T(AV)}	Average On-state Current	Half Cycle, $\Theta = 180^{\circ}$, $T_c = 115^{\circ}C$	0.8	А
I _{TSM}	Non-repetitive On-State Current	Half Cycle, 60 Hz	25	А
I _{TSM}	Non-repetitive On-State Current	Halfl Cycle, 50 Hz	22.5	А
I ² t	Fusing Current	tp = 10 ms, Half Cycle	2.5	A ² s
I _{GM}	Peak Gate Current	20 μs max.	1.2	А
P _{GM}	Peak Gate Dissipation	20 μs max.	3	W
P _{G(AV)}	Gate Dissipation	20ms max.	0.2	W
T _j	Operating Temperature		(-40 to +125)	°C
T _{stg}	Storage Temperature		(-40 to +150)	°C
T _{sld}	Soldering Temperature	10s max.	260	°C

SYMBOL	PARAMETER	CONDITIONS	VOLTAGE			Unit
OTWIDOL			D	М	N	
V _{DRM} /V _{RRM}	Repetitive Peak Off State Voltage	$R_{GK} = 1 \text{ k}\Omega$	400	600	800	V

Revision: 1

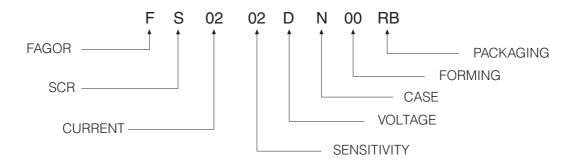


Electrical Characteristics at Tamb = 25 °C

SYMBOL	L PARAMETER CONDITIONS					SENSITIVITY		Unit	
01111202	17.00.000				01	02	03	04	. 0
I _{GT}	Gate Trigger Current	$V_D = 12 V_{DC}, R_L = 140 \Omega. T_j = 25 °C$		MIN	1		20	15	μΑ
a i	391 11 1			MAX	20	200	200	50	
V_{GT}	Gate Trigger Voltage	$V_D = 12 V_{DC}, R_L = 140$,	MAX	X 0.8				V
V_{GD}	Gate Non Trigger Voltage	$V_D = V_{DRM}, R_L = 3.3k\Omega$ $T_j = 125 ^{\circ}C$	$V_D = V_{DRM}$, $R_L = 3.3k\Omega R_{GK} = 220\Omega$ MIN 0.1 $T_i = 125 ^{\circ}C$				V		
V_{RGM}	Reverse Gate Voltage	$I_{RG} = 10\mu A$,		MIN		8			V
I _H	Holding Current	$I_T = 50 \text{ mA}, R_{GK} = 1 \text{ k}\Omega$	$T_{j} = 25 ^{\circ}\text{C}$	MAX	5	5	7	5	mA
IL	Latching Current	I_G = 1 mA, R_{GK} = 1 k Ω		MAX	6	6	7	6	mA
dV / dt	Critical Rate of Voltage Rise	$V_D = 0.67 \times V_{DRM}$, $R_{GK} = 1 \text{ k}\Omega$, $T_i = 125 ^{\circ}\text{C}$		MIN	15	10	30	30	V/µs
dI / dt	Critical Rate of Current Rise	e $I_G = 2 \times I_{GT}$ $tr \le 100 \text{ ns, } f = 60 \text{ Hz,}$ MIN 50				A/µs			
V_{TM}	On-state Voltage	at $I_T = 2.5$ Amp, tp = 380 μ s, $T_j = 25$ °C MAX 1.45		45	2	1.45	V		
V _{t 0}	Threshold Voltage	$T_{\rm j} = 125 ^{\circ}{\rm C}$ MAX 0.90				V			
r _d	Dynamic resistance	$T_{j} = 125 ^{\circ}\text{C}$ MAX 150				m Ω			
I _{DRM} / I _{RRM}	Off-State Leakage Current	$V_D = V_{DRM}$, $R_{GK} = 1k\Omega$ $T_i = 125$ °C MAX 500			μΑ				
Brilly Tilling	on state Islanding			MAX	X 5		μΑ		
$R_{th(j-l)}$	Thermal Resistance Junction-Leads for DC			25		5		°C/W	
R _{th(j-a)}	Thermal Resistance Junction-Amb for DC	$S^{(1)} = 5 \text{ cm}^2$			60			°C/W	

⁽¹⁾ S: Cooper surface under tab.

Part Number Information



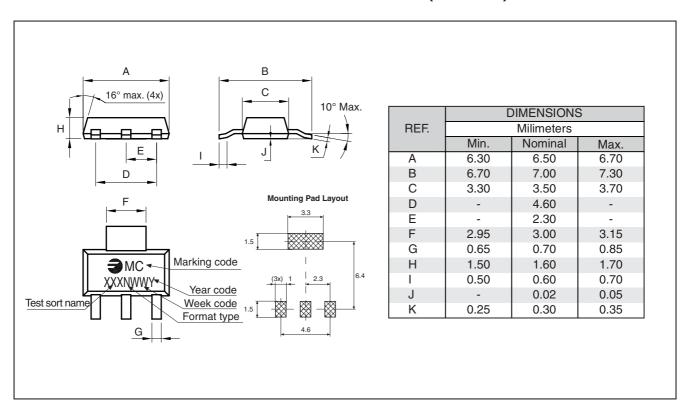
Revision: 1



Ordering information

PREFERRED P/N	PACKAGE CODE	DELIVERY MODE	BASE QUANTITY	UNIT WEIGHT (g)	
FS0202DN 00RS	RS	REEL	1,000	0.116	
FS0202DN 00RB	RB	REEL	2,500	0.116	

Package Outline Dimensions: (mm) TO-261AA (SOT-223)





Ratings and Characteristics (Ta 25 °C unless otherwise noted)

Fig. 1: Maximum average power dissipation versus average on-state current

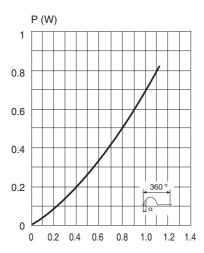


Fig. 3: Relative variation of thermal impedance junction to case versus pulse duration

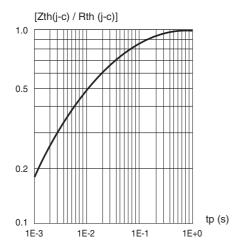


Fig. 5: Relative variation of holding current versus gate-cathode resistance (typical values).

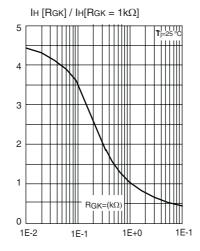


Fig. 2: Average and D.C. on-state current versus case temperature

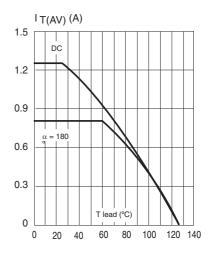


Fig. 4: Relative variation of gate trigger current, holding and latching current versus junction temperature

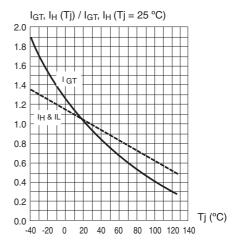


Fig. 6: Relative variation of dV/dt immunity versus gate-cathode resistance (typical values).

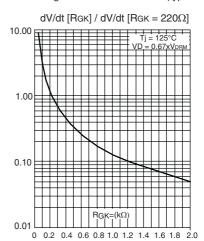




Fig. 7: Relative variation of dV/dt immunity versus gate-cathode capacitance (typical values).

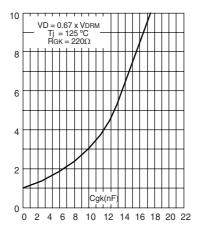


Fig. 9: Non repetitive surge peak on-state current for a sinusoidal pulse with width: tp < 10 ms, and corresponding value of l²t.

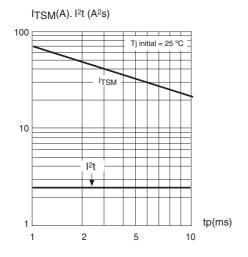


Fig. 8: Non repetitive surge peak on-state current versus number of cycles.

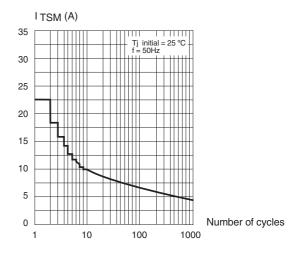
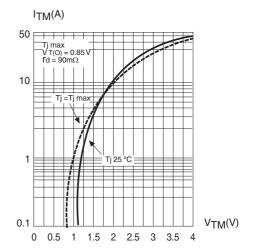


Fig. 10: On-state characteristics (maximum values)





Revision History

Date	Revision	Description of Changes		
14-Sep-2011	0	Original Data Sheet		
27-May-2013 1		200V and 700V eliminated		

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